

# HL6327MG/28MG

AlGaInP Laser Diodes

ODE-208-031 (Z) Rev.0 Jul. 01, 2005

### Description

The HL6327MG/28MG are 0.63  $\mu$ m band AlGaInP laser diodes with a multi-quantum well (MQW) structure. They are suitable as light sources for laser levelers, laser scanners and optical equipment for measurement.

#### Features

- Visible light output : 635 nm Typ
- Single longitudinal mode
- Optical output power : 5 mW CW
- Low operating current : 40 mA Typ
- Low operating voltage : 2.4 V Max
- Operating temperature  $:+50^{\circ}C$
- TM mode oscillation

#### **Absolute Maximum Ratings**

1			
Package Type • HL6327MG/28MG: MG	Internal Circuit	Internal Circuit	
F			

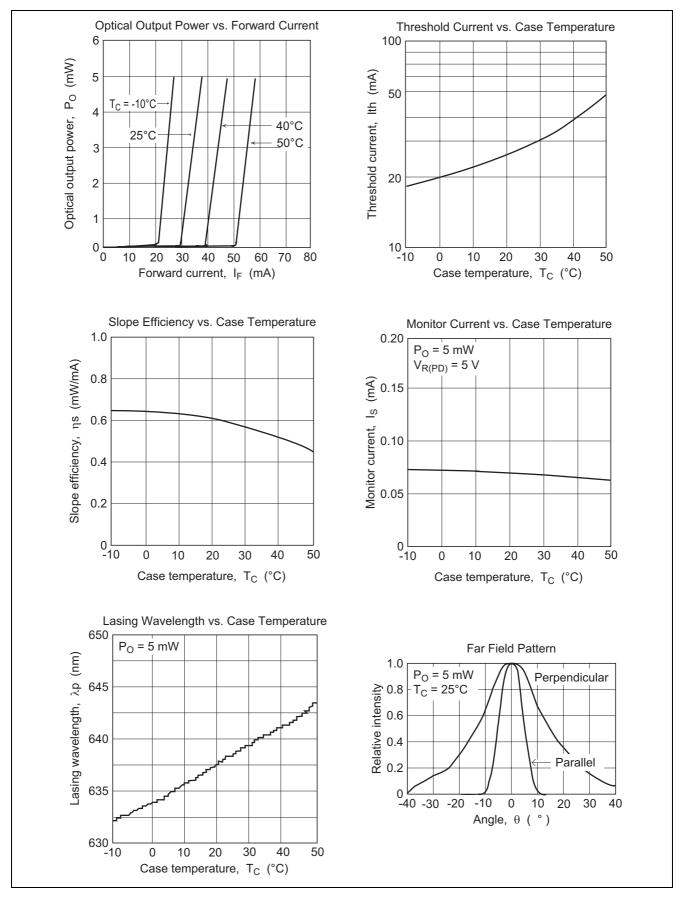
			$(T_{C} = 25^{\circ}C)$	
ltem	Symbol	Ratings	Unit	
Optical output power	Po	5	mW	
LD reverse voltage	V <sub>R(LD)</sub>	2	V	
PD reverse voltage	V <sub>R(PD)</sub>	30	V	
Operating temperature	Topr	-10 to +50	°C	
Storage temperature	Tsta	-40 to +85	°C	

#### **Optical and Electrical Characteristics**

 $(T_{C} = 25^{\circ}C)$ **Test Condition** Item Symbol Min Тур Max Unit Threshold current lth 50 mΑ 30 \_ 40 60  $P_0 = 5 \text{ mW}$ Operating current lop \_\_\_\_ mΑ Operating voltage Vop 2.2 2.4 V  $P_0 = 5 \text{ mW}$ Slope efficiency mW/mA  $3 (mW) / (I_{(4mW)} - I_{(1mW)})$ ηs 0.3 0.5 0.8 o Beam divergence θ// 6 8 11  $P_0 = 5 \text{ mW}$ parallel to the junction 0 Beam divergence  $\theta \bot$ 25 31 37  $P_0 = 5 \text{ mW}$ perpendicular to the junction 635 Lasing wavelength λр 630 640  $P_0 = 5 \text{ mW}$ nm Monitor current 0.02 0.07 0.12 mΑ  $P_O = 5 \text{ mW}, V_{R(PD)} = 5 \text{ V}$ ls

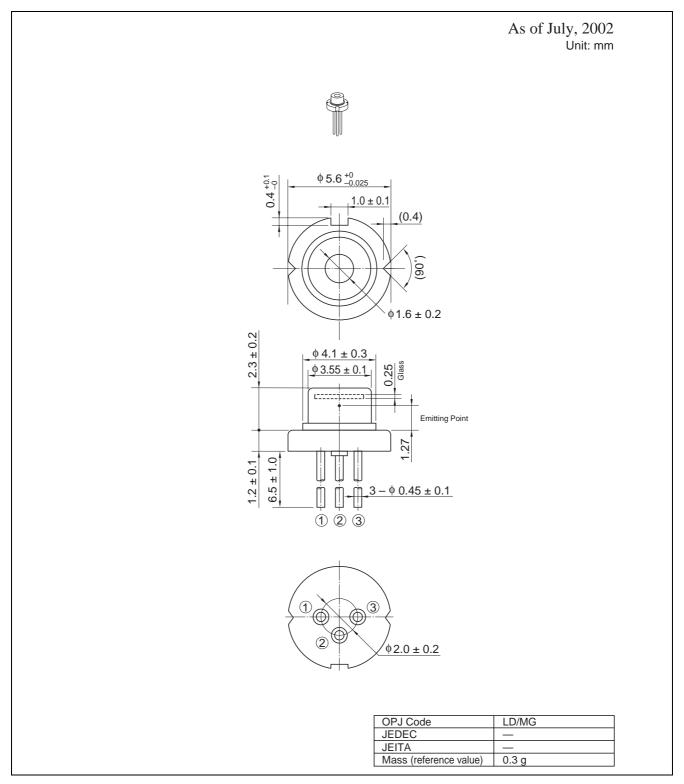


## **Typical Characteristic Curves**





### **Package Dimensions**





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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.

When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

# **Sales Offices**



#### Device Business Unit Opnext Japan, Inc.

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